



#### 40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

#### **Product Summary**

BV <sub>DSS</sub>	RDS(ON) Max	I <sub>D</sub> Max Tc = +25°C
40V	14.8mΩ @ V <sub>GS</sub> = 10V	43.5A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

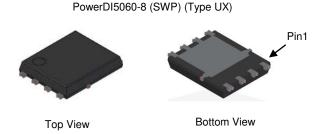
- High Frequency Switching
- Sync Rectification
- DC-DC Converters

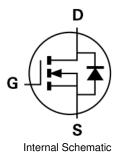
#### **Features**

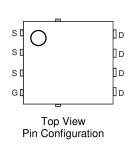
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes Power Losses
- Wettable Flank for Improved Optical Inspection
- Fast Switching Speed
- Low Input Capacitance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

## **Mechanical Data**

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish—Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.097 grams (Approximate)







#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMTH4014SPSW-13	PowerDI5060-8 (SWP) (Type UX)	2500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



);; = Manufacturer's Marking
TH4014SS = Product Type Marking Code

YYWW = Date Code Marking
YY = Year (ex: 21 = 2021)
WW = Week (01 to 53)



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	40	V
Gate-Source Voltage		$V_{GSS}$	±20	V
Continuous Drain Current (Note 6)	T <sub>C</sub> = +25°C	ΙD	43.5	Α
Continuous Diam Current (Note 6)	$T_{C} = +100^{\circ}C$		30.8	
Maximum Continuous Body Diode Forward Current (Note 6)		Is	43.5	Α
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	170	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Ism	170	Α
Avalanche Current, L=0.1mH		las	19.7	Α
Avalanche Energy, L=0.1mH		Eas	19.4	mJ

## **Thermal Characteristics**

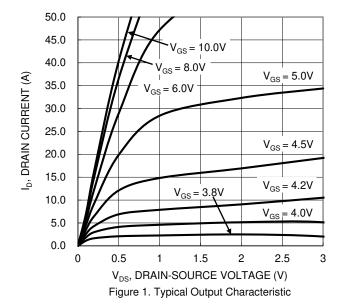
Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	4	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	38	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	46.9	W
Thermal Resistance, Junction to Case (Note 6)	Rejc	3.2	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +175	°C	

## Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Obavastavistis	Currele el	Min	T	May	l limit	Took Condition	
Characteristic OFF CHARACTERISTICS (Note 7)	Symbol	Min	Тур	Max	Unit	Test Condition	
\ /	D) /	40	l	l		N 0V 1 4 A	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	40	_		V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 32V$ , $V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	2	_	4	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	11.4	14.8	mΩ	$V_{GS} = 10V, I_D = 20A$	
Diode Forward Voltage	VsD	_	0.9	1.2	V	$V_{GS} = 0V$ , $I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	805	_		$V_{DS} = 20V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Output Capacitance	Coss	_	208	_	pF		
Reverse Transfer Capacitance	Crss	_	15	_			
Gate Resistance	Rg	_	1.2	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg	_	10.6	_			
Gate-Source Charge	Qgs	_	2.2	_	nC	V <sub>DD</sub> = 20V, I <sub>D</sub> = 20A, V <sub>GS</sub> = 10V	
Gate-Drain Charge	$Q_{gd}$	_	2.7	_			
Turn-On Delay Time	td(ON)	_	4.1	_			
Turn-On Rise Time	tr	_	3.8	_	ns	$\begin{split} V_{GS} &= 20V,  V_{DS} = 10V, \\ R_g &= 1.6\Omega,  I_D = 20A \end{split}$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	8.6	_	115		
Turn-Off Fall Time	tF	_	1.9	_			
Body Diode Reverse Recovery Time	trr	_	10.2	_	ns	Is 154 di/dt 4004/us	
Body Diode Reverse Recovery Charge	Qrr	_	9.6	_	nC	$I_F = 15A$ , di/dt = 400A/ $\mu$ s	

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
- 6. Thermal resistance from junction to soldering point (on the exposed drain pad).7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to product testing.





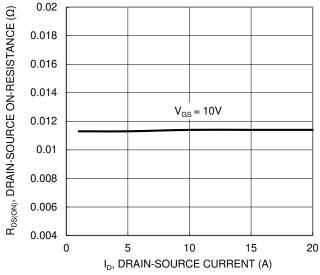


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

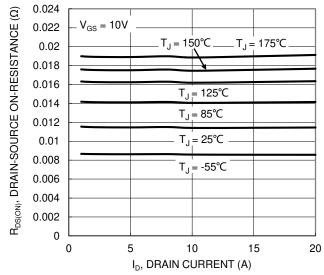


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

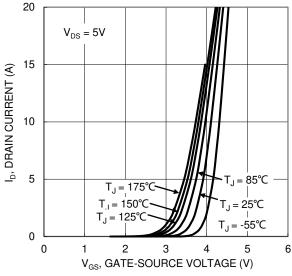


Figure 2. Typical Transfer Characteristic

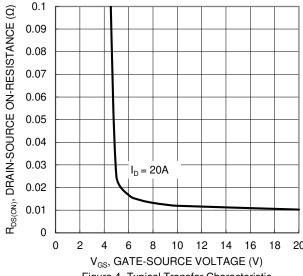


Figure 4. Typical Transfer Characteristic

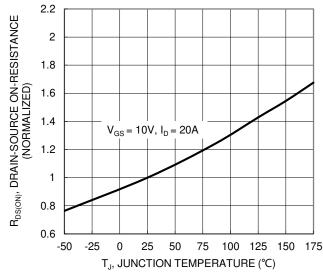


Figure 6. On-Resistance Variation with Junction Temperature



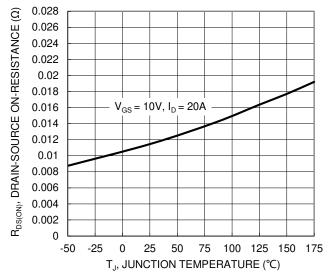


Figure 7. On-Resistance Variation with Junction Temperature

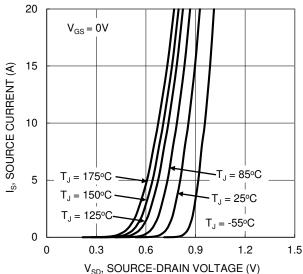


Figure 9. Diode Forward Voltage vs. Current

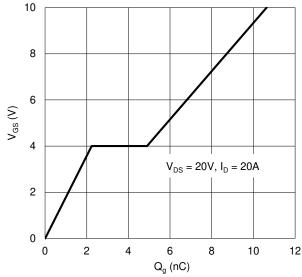


Figure 11. Gate Charge

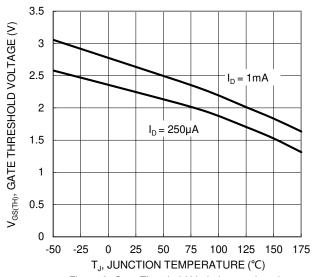


Figure 8. Gate Threshold Variation vs. Junction Temperature

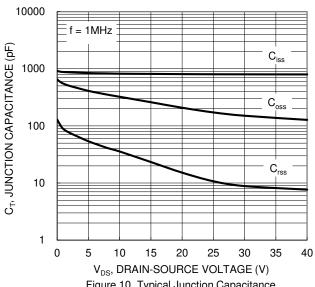


Figure 10. Typical Junction Capacitance

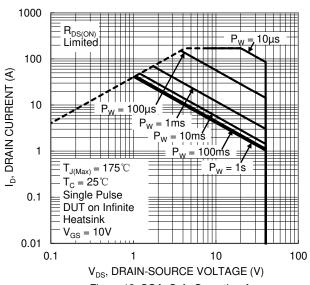


Figure 12. SOA, Safe Operation Area



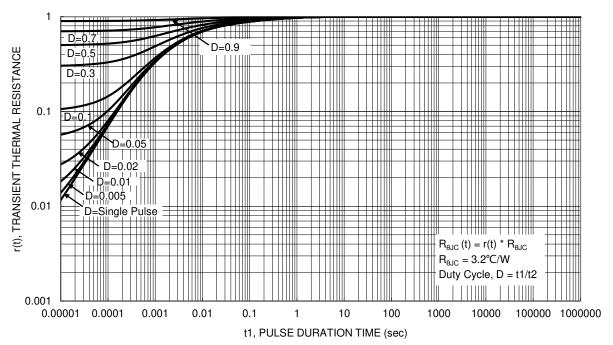


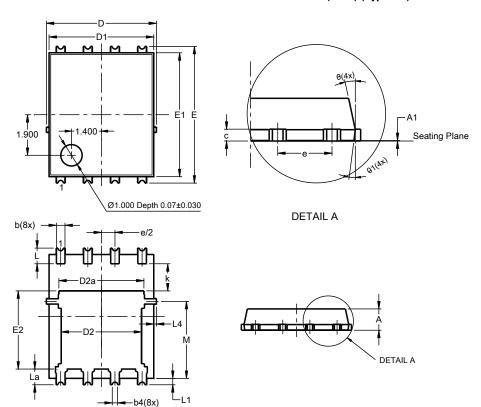
Figure 13. Transient Thermal Resistance



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8 (SWP) (Type UX)

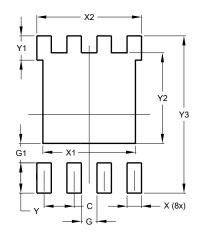


Pov	PowerDI5060-8 (SWP) (Type UX)					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0	0.05				
b	0.30	0.50	0.41			
b2	0.20	0.35	0.25			
b4	(	).25REF	•			
С	0.230	0.330	0.277			
D	5	.15 BS0	)			
D1	4.70	5.10	4.90			
D2	3.56	3.96	3.76			
D2a	3.78 4.18		3.98			
Е	6.40 BSC					
E1	5.60	6.00	5.80			
E2	3.46	3.86	3.66			
E2a	4.195	4.595	4.395			
е	1	.27BSC	)			
k	1.05		-			
L	0.635	0.835	0.735			
La	0.635	0.835	0.735			
L1	0.200 0.400		0.300			
L1a	0.050REF					
L4	0.025	0.225	0.125			
М	3.205	4.005	3.605			
θ	10° 12°		11°			
θ1	6° 8° 7°		,			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value		
פווטופווסוווט	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	4.100		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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